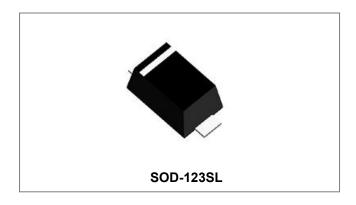






FFM107 SUFACE MOUNT FAST RECOVERY RECTIFIER



Features

- Glass passivated device
- Ideal for surface mouted applications
- Low reverse leakage
- Metallurgically bonded construction
- High temperature soldering guaranteed: 260 C/10 seconds,0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension
- Glass passivated chip junction
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: JEDEC SOD-123SL molded plastic
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- **Mounting Position: Any**
- Weight: 0.0007 ounce, 0.02 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%

Characteristic	Symbol	FFM107	Units
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	V _{RRM} V _{DC}	1000	V
Maximum RMS voltage	V _{RMS}	700	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at @T _A = 65°C	I _(AV)	1.2	А
Peak forward surge current 8.3ms single half sinewave superimposed on rated load (JEDEC Method)	I _{FSM}	50	A
Maximum instantaneous forward voltage at 1.2A	V _F	1.3	V
Maximum DC reverse current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 125°C	I _R	5.0 50.0	μA
Maximum reverse recovery time (Note 2)	t _{rr}	250	ns
Typical Junction Capacitance (Note 3)	Сл	15	pF
Typical Thermal Resistance (Note 1)	R _{0JA}	50	°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150	°C

Note: 1. Averaged over any 20ms period.

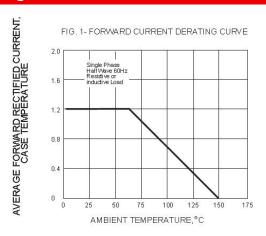
- 2. Measured with IF=0.5A, IR=1A, Irr=0.25A.
- 3. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
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 sales@ smc-diodes.com

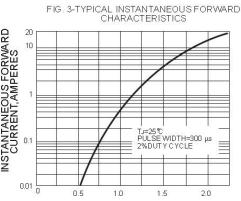




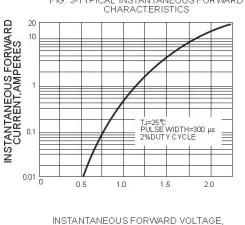


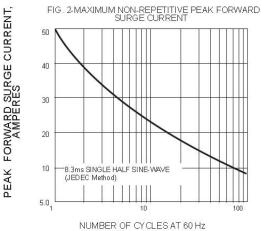
Ratings and Characteristics Curves



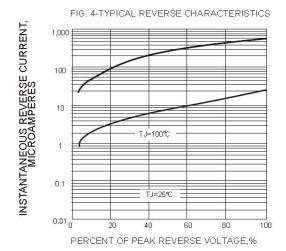


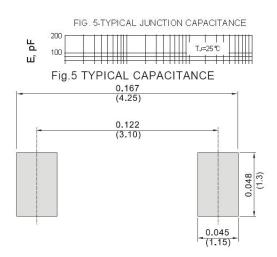
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

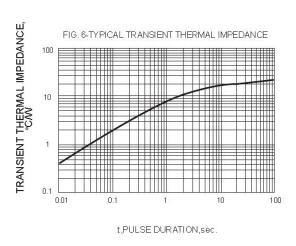












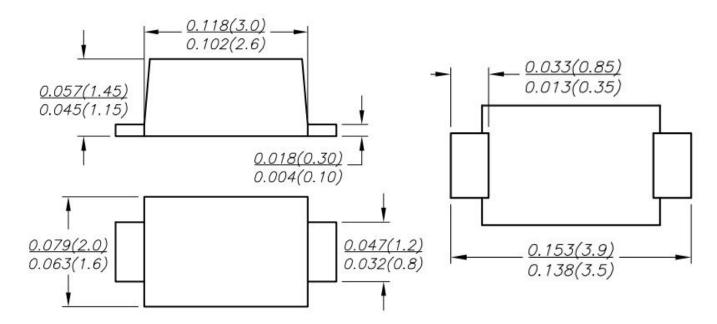
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Mechanical Dimensions SOD-123SL(Inches/Millimeters)

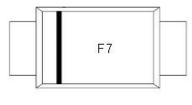


Ordering Information

Device	Package	Shipping	
FFM107	SOD-123SL	E000mag / roal	
	(Pb-Free)	5000pcs / reel	

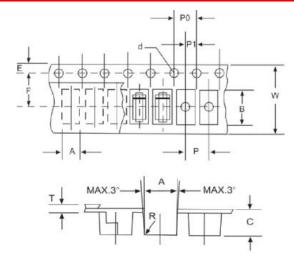
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



F7 = Part Number

Carrier Tape Specification SOD-123SL



SYMBOL	Millimeters		
	Min.	Max.	
Α	2.05	2.25	
В	3.85	4.05	
С	1.25	1.45	
d	1.45	1.65	
Е	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

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